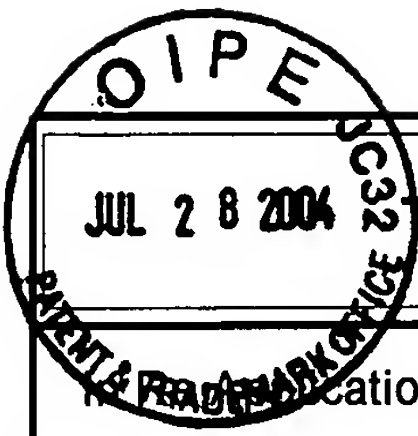


IFW



JUL 28 2004

TRANSMITTAL OF FORMAL DRAWINGS

Docket No.
YOR920030218US1 (16714)

Inventor: Cyril Cabral, Jr., et al.

Application No.	Filing Date	Confirmation No.	Examiner	Customer No.	Group Art Unit
10/662,900	9/15/2003	Unassigned	Unassigned	23389	Unassigned

Invention: **REDUCTION OF SILICIDE FORMATION TEMPERATURE ON SiGe CONTAINING SUBSTRATES**

Address to:
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Transmitted herewith are:

7 sheets of formal drawing(s) for this application.

☒ Each sheet of drawing indicates the identifying indicia suggested in 37 CFR Section 1.84(c).

Signature

Leslie S. Szivos, Ph.D.
Registration No. 39,394

Dated: July 26, 2004

I certify that this document and attached formal drawings are being deposited on 7/26/2004 with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Signature of Person Mailing Correspondence

Leslie S. Szivos, Ph.D.

Typed or Printed Name of Person Mailing Correspondence